Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

TPCA8025

Lithium-Ion Battery Applications
Notebook PC Applications
Portable Equipment Applications

• Small footprint due to a small and thin package

• Low drain-source ON-resistance: $RDS(ON) = 2.7 \text{ m}\Omega \text{ (typ.)}$

• High forward transfer admittance: $|Y_{fs}| = 80S$ (typ.)

• Low leakage current: $IDSS = 10 \mu A (max) (VDS = 30 V)$

• Enhancement mode: $V_{th} = 1.3 \text{ to } 2.5 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

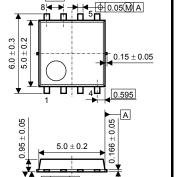
Characte	ristics	Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	30	V	
Drain-gate voltage (R	GS = 20 kΩ)	V_{DGR}	30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1)	I _D	40	Α	
Diain current	Pulsed (Note 1)	I_{DP}	120	A	
Drain power dissipation	on (Tc = 25°C)	P_{D}	45	W	
Drain power dissipation	on (t = 10 s) (Note 2a)	P_{D}	2.8	W	
Drain power dissipation	on (t = 10 s) (Note 2b)	P _D	1.6	W	
Single pulse avalanch	ne energy (Note 3)	E _{AS}	208	mJ	
Avalanche current		I _{AR}	40	Α	
Repetitive avalanche	energy c = 25°C) (Note 4)	E _{AR}	4.5	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature	range	T _{stg}	–55 to 150	°C	

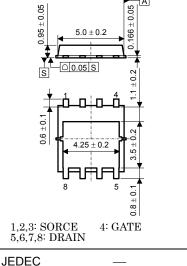
Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.





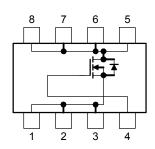
Weight: 0.069 g (typ.)

JEITA

TOSHIBA

Circuit Configuration

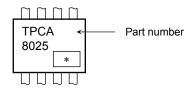
2-5Q1A



Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2b)	R _{th (ch-a)}	78.1	°C/W

Marking (Note 5)

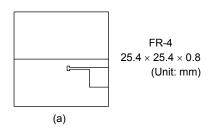


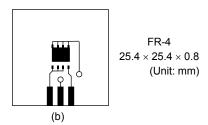
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:

(a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD} = 24~V,~T_{ch} = 25^{\circ}C$ (initial), L = 0.1mH, R_G = 25 $\Omega,~I_{AR} = 40~A$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: *Weekly code: (Three digits)



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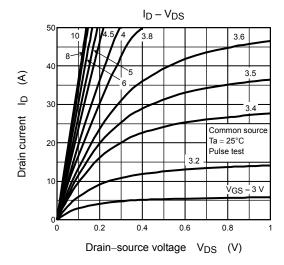
Electrical Characteristics (Ta = 25°C)

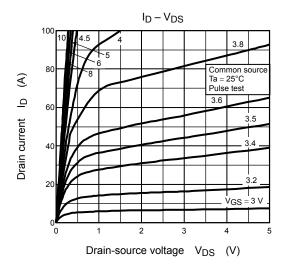
Ch	aracteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cut-OFF cu	ırrent	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	μА
Drain-source bre	akdown voltage	V _{(BR) DSS}	$I_D = 10$ mA, $V_{GS} = 0$ V	30	_		V
Diam-source bre	ardown voltage	V _{(BR) DSX}	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	10	1.3 — 2.5 — 4.2 6 — 2.7 3.5 40 80 — — 2200 — — 430 —		·
Gate threshold ve	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	1.3		2.5	>
Drain-source ON	-resistance	D	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		4.2	6	mΩ
Drain-source ON-resistance Forward transfer admittance		R _{DS} (ON)	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		2.7	3.5	11122
Forward transfer admittance		Y _{fs}	$V_{DS} = 10 \text{ V}, I_D = 20 \text{ A}$	40	80	_	S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	2200	_	pF
Reverse transfer capacitance		C _{rss}		_	430	_	
Output capacitance		C _{oss}		_	690	_	
	Rise time	t _r	, 10 V		12		
Cuitobing time	Turn-ON time	t _{on}	V _{GS} 10 V	_	22	_	
Switching time	Fall time	t _f	4.7 Ω (4.7 Ω (4.	_	23	_	ns
	Turn-OFF time	t _{off}	$V_{DD} \approx 15 \text{ V}$ Duty \leq 1%, $t_{W} = 10 \mu\text{s}$	_	74	_	
Total gate charge (gate-source plus gate-drain)		Qg			49		
Gate-source charge 1		Q _{gs1}	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 40 \text{ A}$		8.5		nC
Gate-drain ("miller") charge		Q _{gd}		_	16	_	

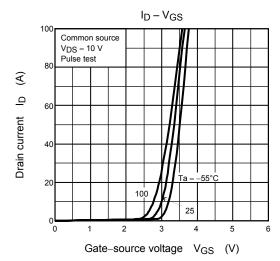
Source-Drain Ratings and Characteristics (Ta = 25°C)

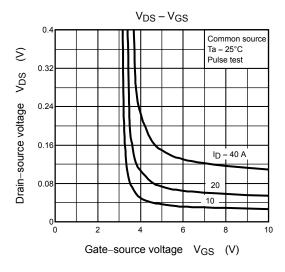
Characteri	stics		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse	(Note 1)	I _{DRP}	_	_	_	120	Α
Forward voltage (diode)			V_{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_	_	-1.2	٧

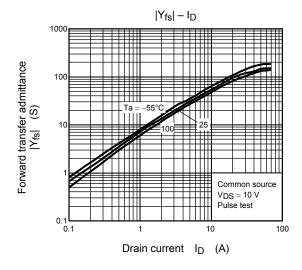
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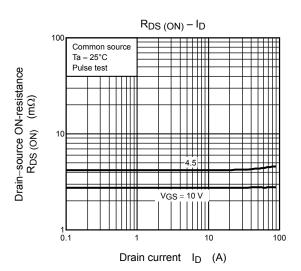


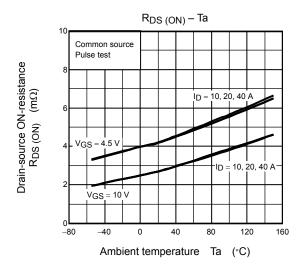


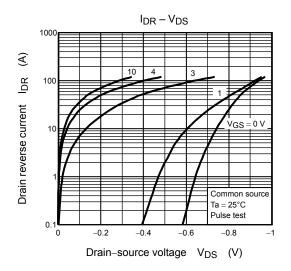


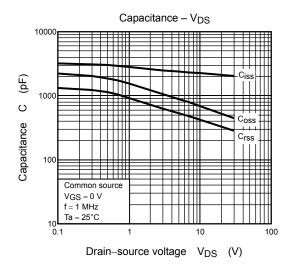


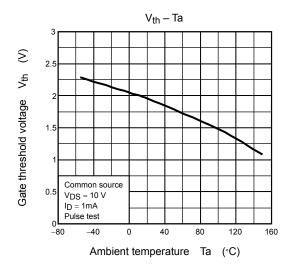


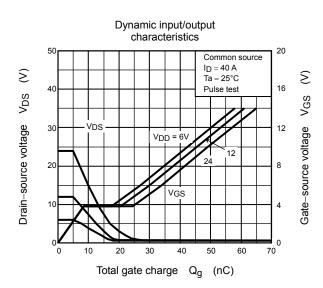




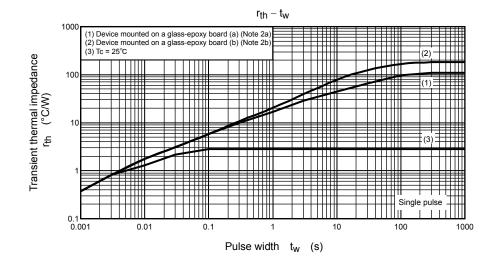


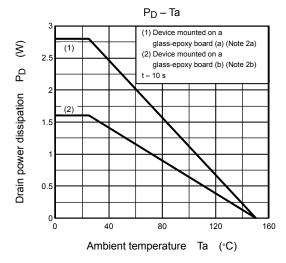


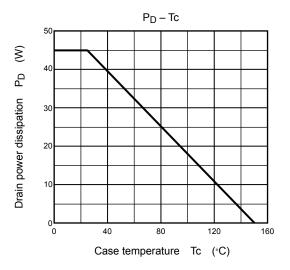


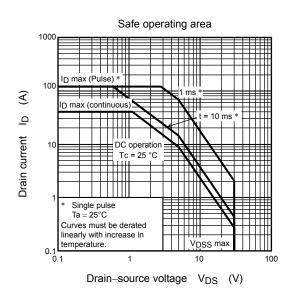


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